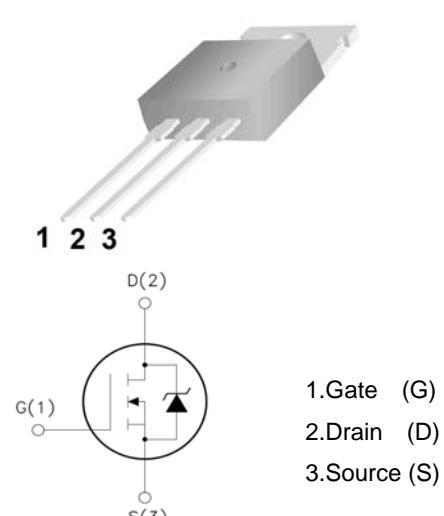


<p>Features:</p> <ul style="list-style-type: none"> <input type="checkbox"/> Low Intrinsic Capacitances. <input type="checkbox"/> Excellent Switching Characteristics. <input type="checkbox"/> Extended Safe Operating Area. <input type="checkbox"/> Unrivalled Gate Charge :$Q_g = 155\text{nC}$ (Typ.). <input type="checkbox"/> $\text{BV}_{\text{DSS}}=100\text{V}, I_{\text{D}}=180\text{A}$ <input type="checkbox"/> $R_{\text{DS}(\text{on})} : 5\text{m}\Omega$ (Max) @$V_{\text{G}}=10\text{V}$ <input type="checkbox"/> 100% Avalanche Tested 	<p>TO-220</p>  
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Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Maximum	Unit
V_{DSS}	Drain-to-Source Voltage	100	V
V_{GSS}	Gate-to-Source Voltage	± 25	V
I_D^3	Continuous Drain Current	180	A
	$T_C=100^\circ\text{C}$	130	
I_{DP}^4	Pulsed Drain Current	600	
I_{AS}^5	Avalanche Current	40	
E_{AS}^5	Avalanche energy	700	mJ
P_D	Maximum Power Dissipation	240	W
	$T_C=100^\circ\text{C}$	125	
T_J, T_{STG}	Junction & Storage Temperature Range	-55~175	°C

Thermal Characteristics

Symbol	Parameter	Typical	Unit
$R_{\theta\text{jc}}$	Thermal Resistance-Junction to Case	0.6	°C/W
$R_{\theta\text{ja}}$	Thermal Resistance-Junction to Ambient	62.5	

Electrical Characteristics (TA=25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Typ	Max.	Unit
Static Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	100	—	—	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =80V, V _{GS} =0V	—	—	1	uA
		T _J =125°C	—	—	100	
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	2	3	4	V
I _{GSS}	Gate Leakage Current	V _{GS} =±25V, V _{DS} =0V	—	—	±100	nA
R _{DS(on)} ¹	Drain-Source On-Resistance	V _{GS} =10V, I _D =40A	—	4.5	5	mΩ
		—	—	—	—	
Diode Characteristics						
V _{SD} ¹	Diode Forward Voltage	I _{SD} =40A, V _{GS} =0V	—	0.8	1.3	V
I _s ³	Diode Continuous Forward Current	—	—	—	180	A
t _{rr}	Reverse Recovery Time	I _F =40A, dI/dt=100A/us	—	65	—	nS
Q _{rr}	Reverse Recovery Charge		—	103	—	nC
Dynamic Characteristics ²						
R _G	Gate Resistance	V _{GS} =0V, V _{DS} =0V, Frequency=1MHz	—	2.5	—	Ω
C _{iss}	Input Capacitance	V _{GS} =0V, V _{DS} =25V Frequency=1MHz	—	7850	—	pF
C _{oss}	Output Capacitance		—	1010	—	
C _{rss}	Reverse Transfer Capacitance		—	630	—	
t _{d(on)}	Turn-On Delay Time	—	28	—	nS	
t _r	Rise Time	V _{DD} =37.5V, I _D =40A, V _{GS} =10V, R _G =6.8Ω	—	45		
t _{d(off)}	Turn-Off Delay Time		—	84		
t _f	Fall Time		—	49		
Gate Charge Characteristics ²						
Q _g	Total Gate Charge	V _{DS} =37.5V, V _{GS} =10V I _D =40A	—	184	—	nC
Q _{gs}	Gate-to-Source Charge		—	33	—	
Q _{gd}	Gate-to-Drain Charge		—	60	—	

Note: 1: Pulse test; pulse width \leq 300us, duty cycle \leq 2%.

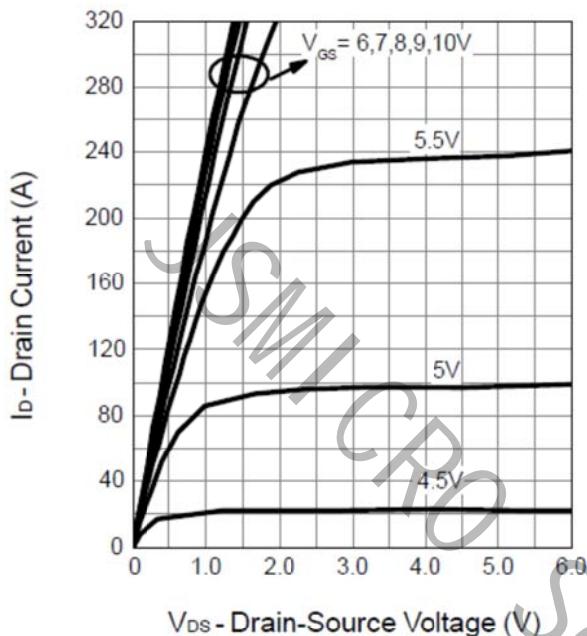
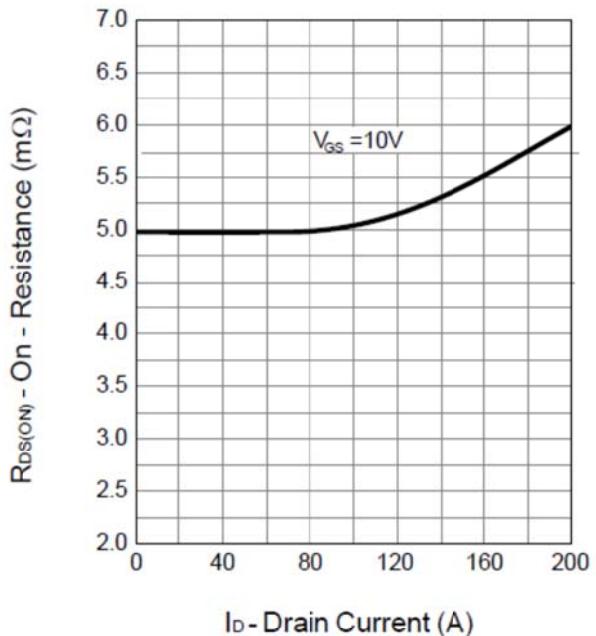
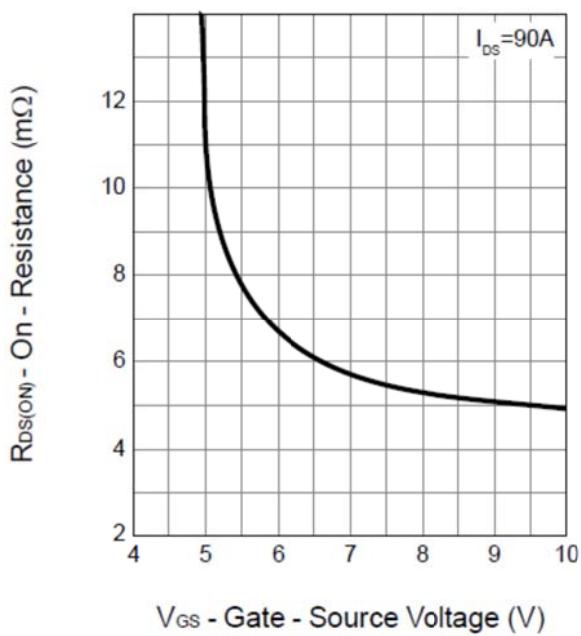
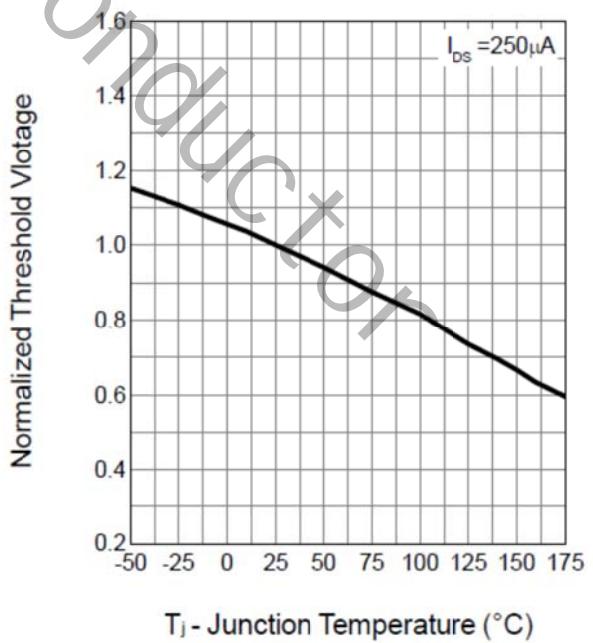
2: Guaranteed by design, not subject to production testing.

3: Package limitation current is 50A.Calculated continuous current based on maximum allowable junction temperature.

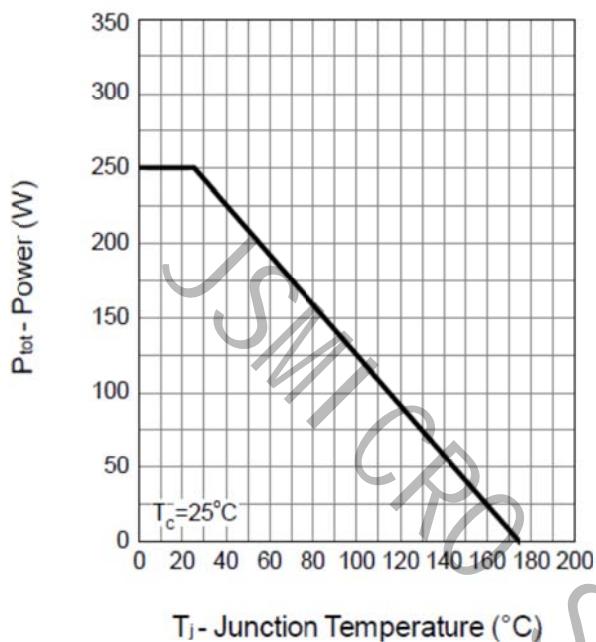
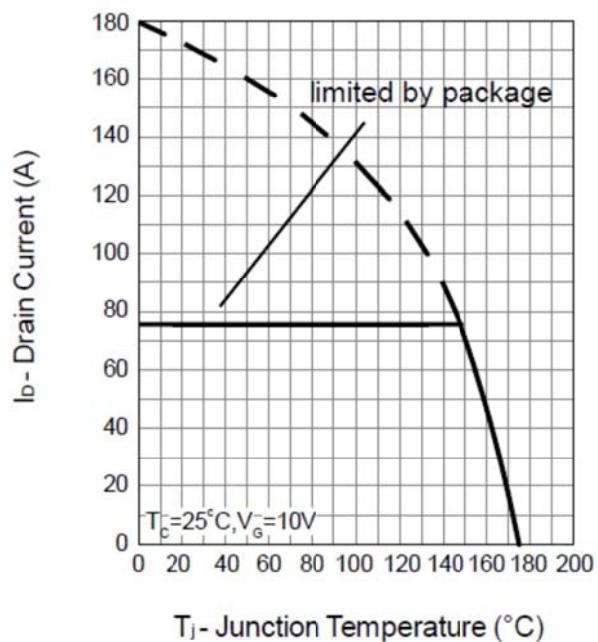
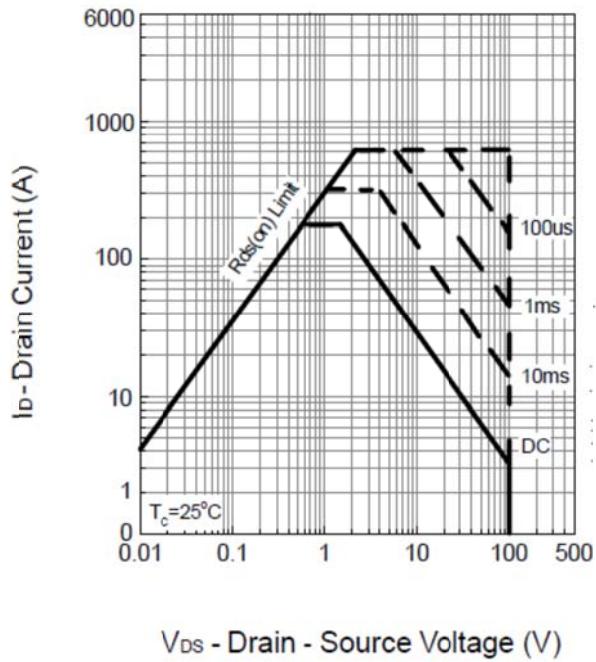
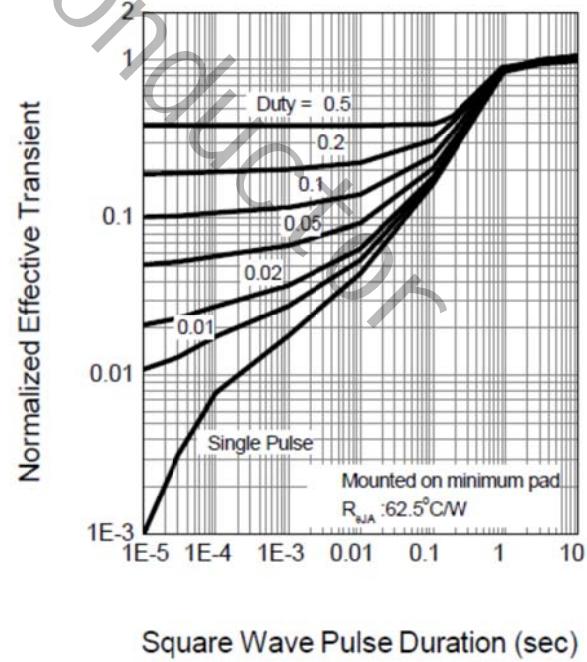
4: Repetitive rating, pulse width limited by max junction temperature.

5: Starting TJ = 25°C,L = 0.5mH, VDD=80V, IAS = 74A.

Typical Characteristics

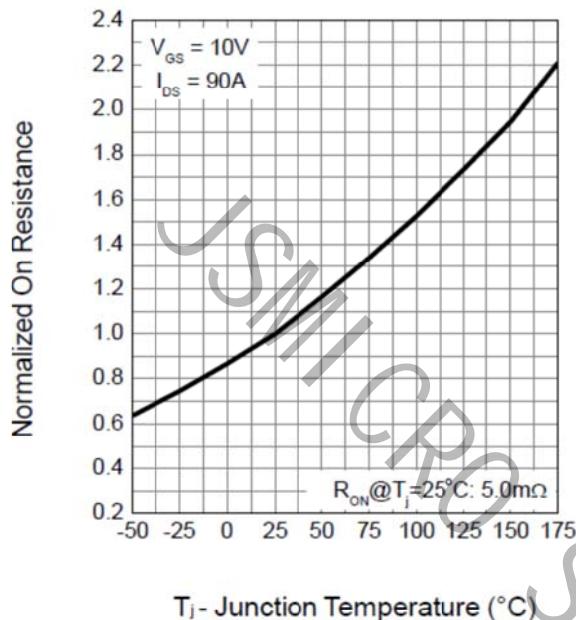
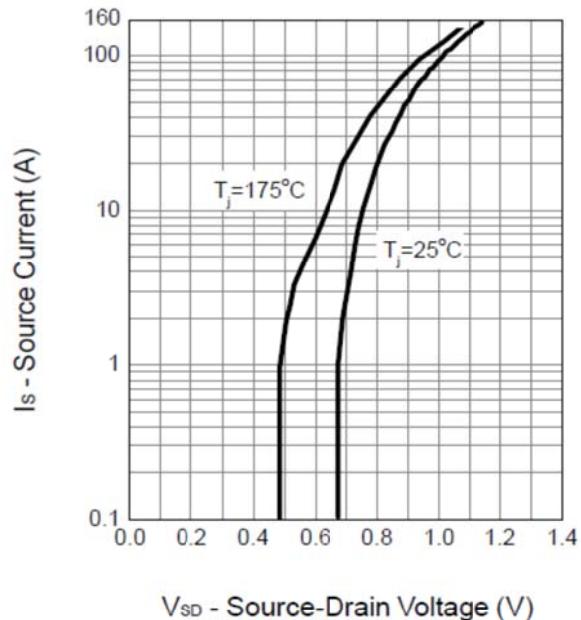
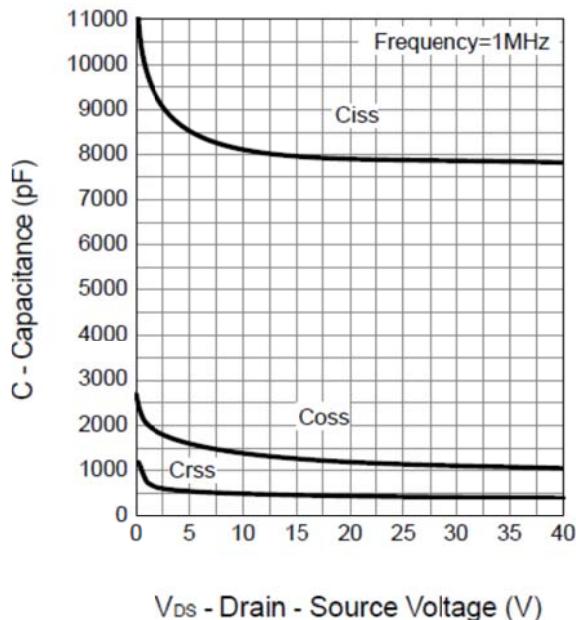
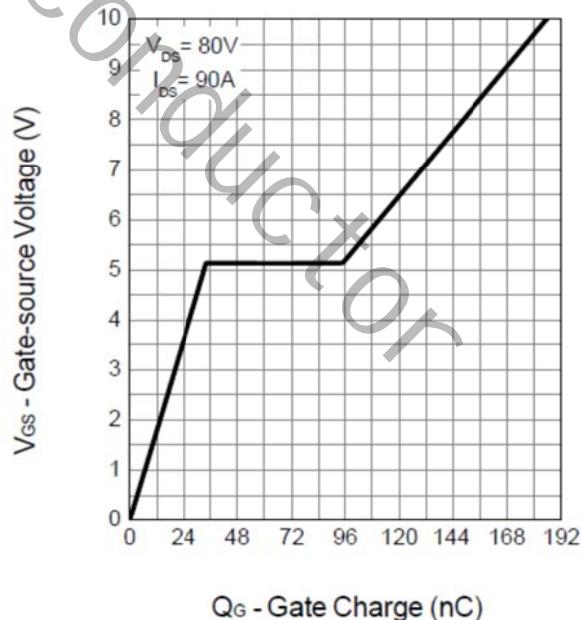
Output Characteristics

Drain-Source On Resistance

Drain-Source On Resistance

Gate Threshold Voltage


Typical Characteristics (Continued)

Power Dissipation

Drain Current

Safe Operation Area

Thermal Transient Impedance

 V_{DS} - Drain - Source Voltage (V)

Square Wave Pulse Duration (sec)

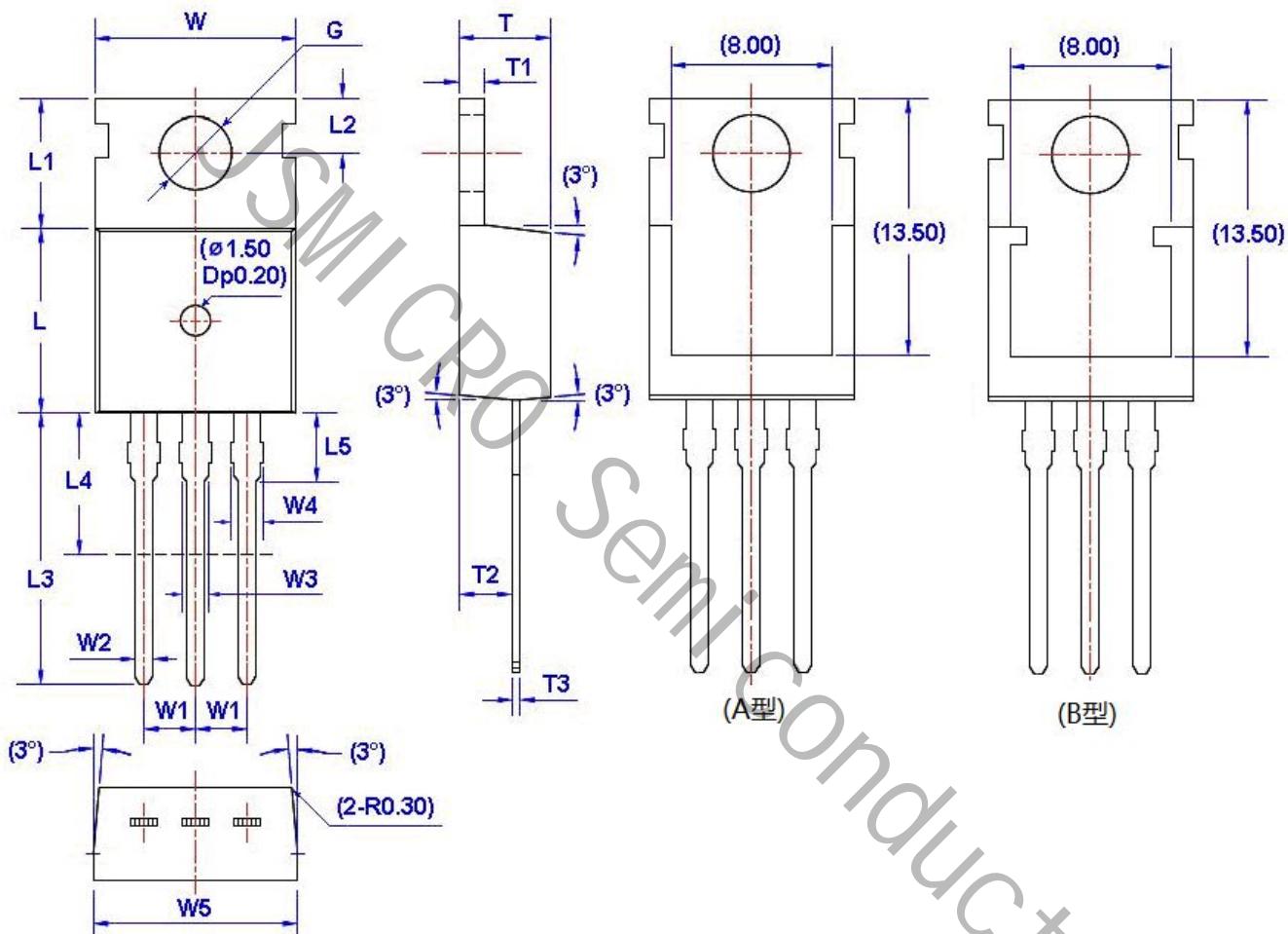
Typical Characteristics (Continued)

Drain-Source On Resistance

Source-Drain Diode Forward

Capacitance

Gate Charge


Package Dimension

TO-220

Unit:mm



Symbol	Size		Symbol	Size		Symbol	Size		Symbol	Size	
	Min	Max		Min	Max		Min	Max		Min	Max
W	9.66	10.28	W5	9.80	10.20	L4**	6.20	6.60	T3	0.45	0.60
W1	2.54 (TYP)		L	9.00	9.40	L5	2.79	3.30	G(Φ)	3.50	3.70
W2	0.70	0.95	L1	6.40	6.80	T	4.30	4.70			
W3	1.17	1.37	L2	2.70	2.90	T1	1.15	1.40			
W4*	1.32	1.72	L3	12.70	14.27	T2	2.20	2.60			